## NSN 5961-00-754-5693

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-754-5693 **Inclosure Material:** Metal **Overall Length:** 1.265 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** 0.445 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 32.0 breakdown voltage, instantaneous **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 150.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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